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***Etron***

High-Performance Semiconductors  
Memory, Visual, and Interface  
Solutions

IMSE-189

Residual bulk image characterization  
using photon transfer techniques

Richard Crisp, Etron Technology America

## Outline

- Company Overview
- R&D Workbench: Camera EO Characterization
- Trapped Charge Issues with PTC Characterization
- Using PTC methods for Charge Trapping Measurement
- Residual image management

# Company Profile

## Etron Technology

- Founded in 1991 as memory company
- Headquarters: Hsinchu Science Park, Taiwan
- IPO (TPEX: 5351.TW) in 1998
- Fabless business model from inception

## Today (as of September 2016)

- Shareholder's equity: US \$132M
- Assets: US \$248M
- Patents: 563
- Employees: 470



## Memory

- Pioneering Application-Driven Buffer Memory
- Leader of Known-Good-Die Memory Products

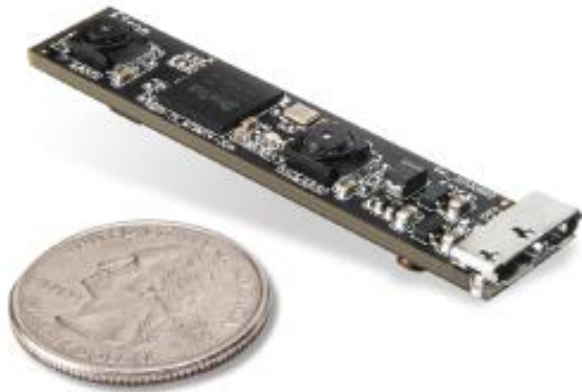
## Imaging

- 3D Cameras and Controller ICs
- 360° Cameras and ICs

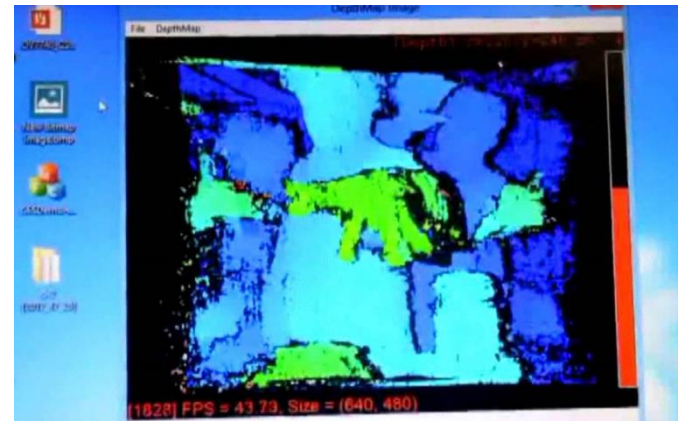
# Etron Imaging Products



ASICs for  
360 degree  
Spherical Cameras



ASICs for  
Stereoscopic  
3D Depthmap  
Cameras



**Today we talk about what we do back  
in the lab, not the products we build!**

# R&D Workbench: Camera EO Characterization

## Important performance metrics often needed for design, calibration & optimization

- Read Noise
- Camera Gain
- Saturation Signal
- PRNU
- DSNU
- Linearity

## Photon Transfer Methods are often used

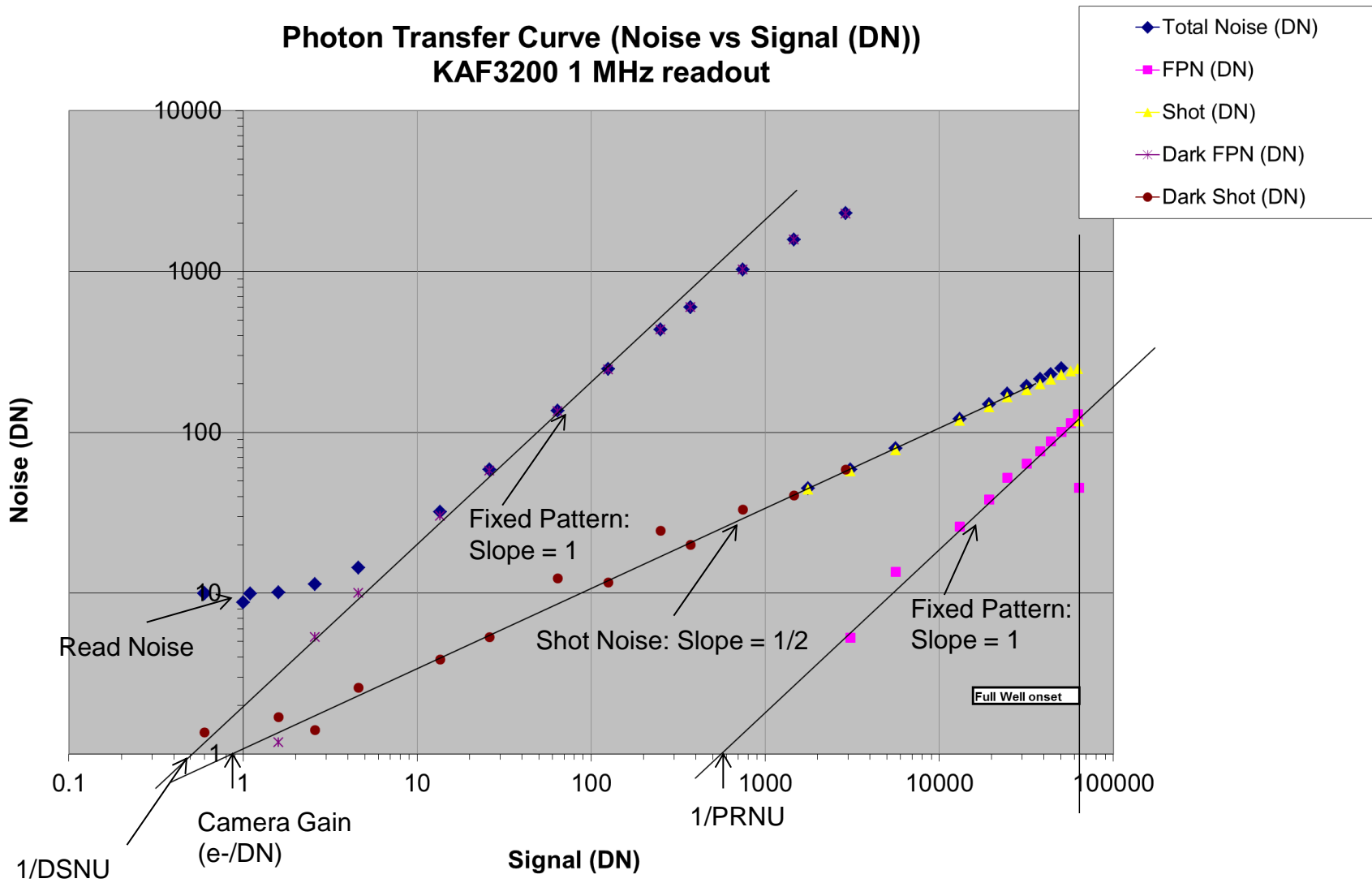
- Decomposes camera output into components using basic mathematical relationships
- Graphical method: plots noise against signal
- Simple equipment and procedure: light source, camera, spreadsheet
- Avoids need for calibrated source, calibrated photodiode  
“Can do at home on your kitchen table”

# Photon Transfer Basics

## Write Equations for Noise considering relevant parameters

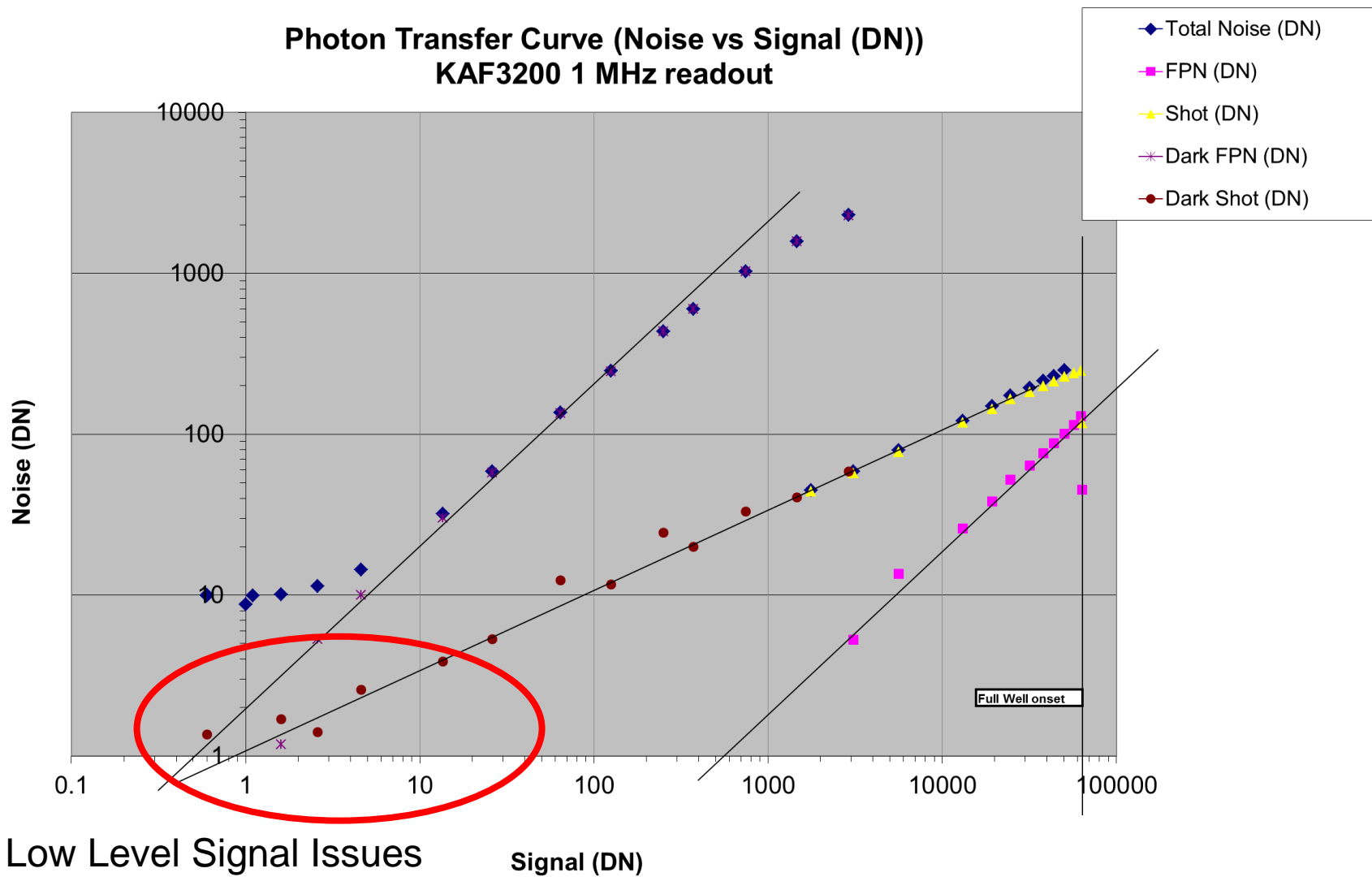
- Common ones
  - Total noise
  - Read Noise
  - Fixed Pattern Noise
  - Signal Shot Noise
  - Dark Shot Noise
  - Dark Fixed Pattern Noise
  - Camera Gain
- Capture pairs of identical flat field and dark exposures ranging from very low level to full well
- Measure std deviation of 100 x 100 pixel region and average values in each frame
- Make difference frames of pairs of identical exposures and measure std deviation
- Compute and plot desired noise components versus signal or versus time
  - Use logarithmic axes to cover many orders of magnitude
- Plot light-on and dark signal data on same graph
  - Easy way to extend from very low signal to full well
- Look for straight lines and slopes for shot noise & fixed pattern noise
- Look for intercepts for gain, PRNU, DSNU, read-noise

### Photon Transfer Curve (Noise vs Signal (DN)) KAF3200 1 MHz readout

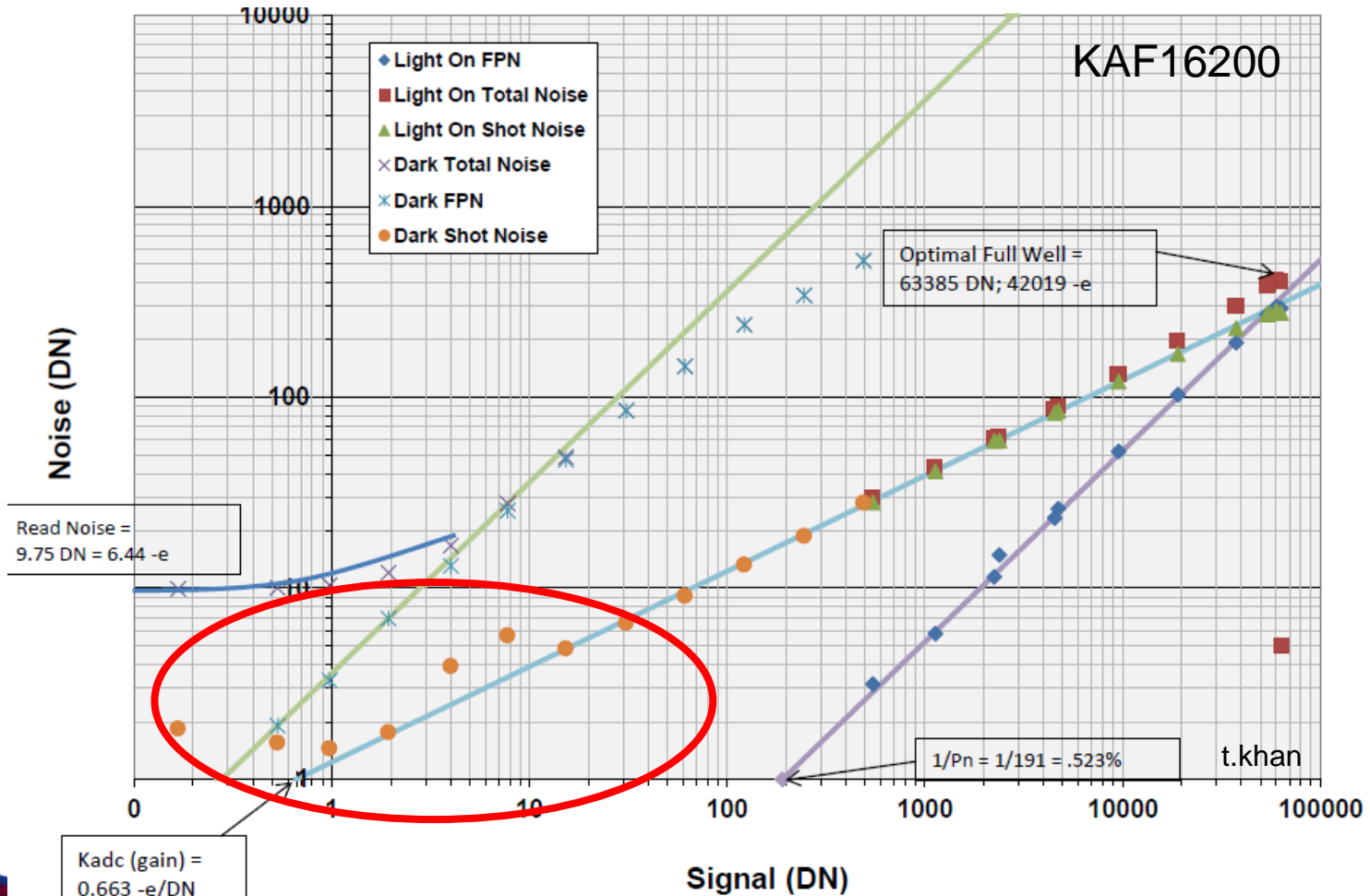




Photon Transfer Curve (Noise vs Signal (DN))  
KAF3200 1 MHz readout



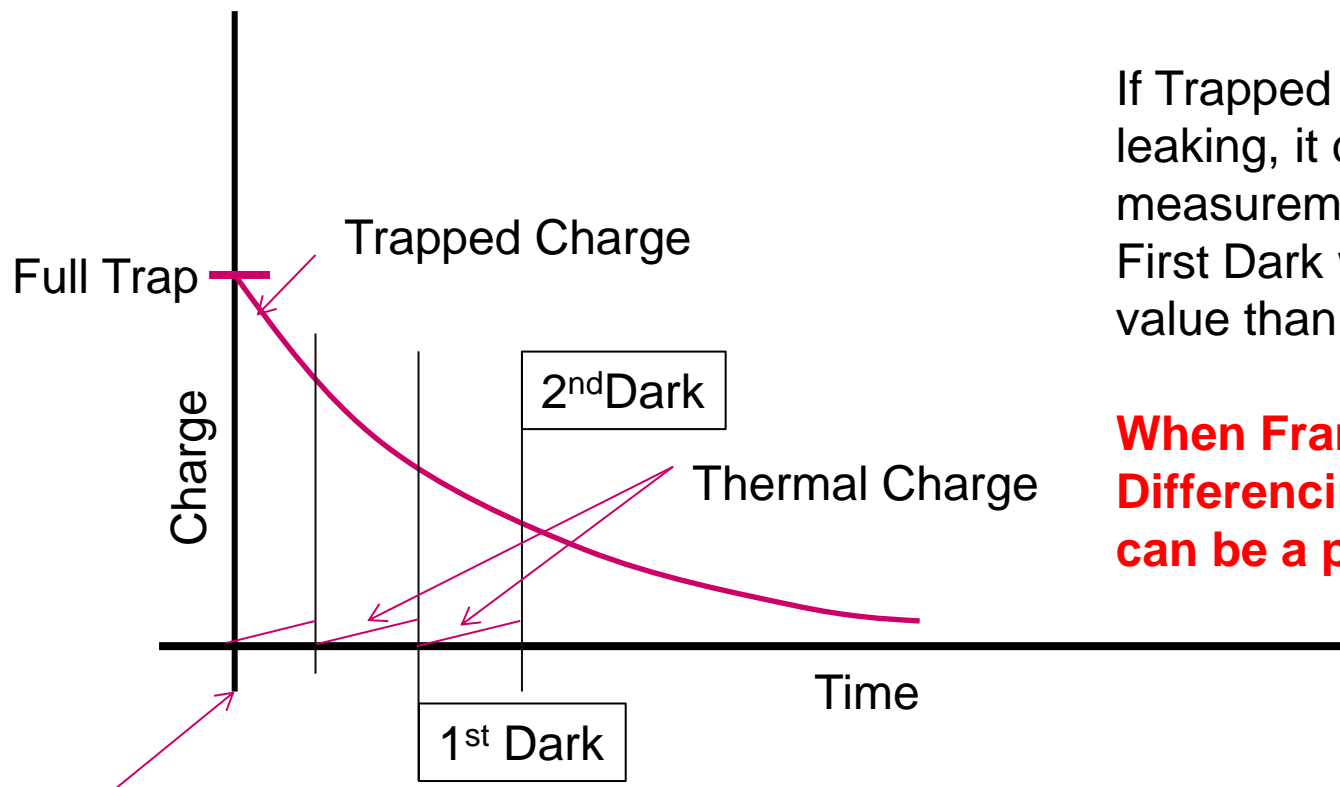
# Trapped Charge: Hazard for PTCs, No flushing before cooling after power-up



Kadc (gain) = 0.663 -e/DN

Low Level Signal Issues

# Low Level Signal Issues: differencing exposures in presence of trapped charge

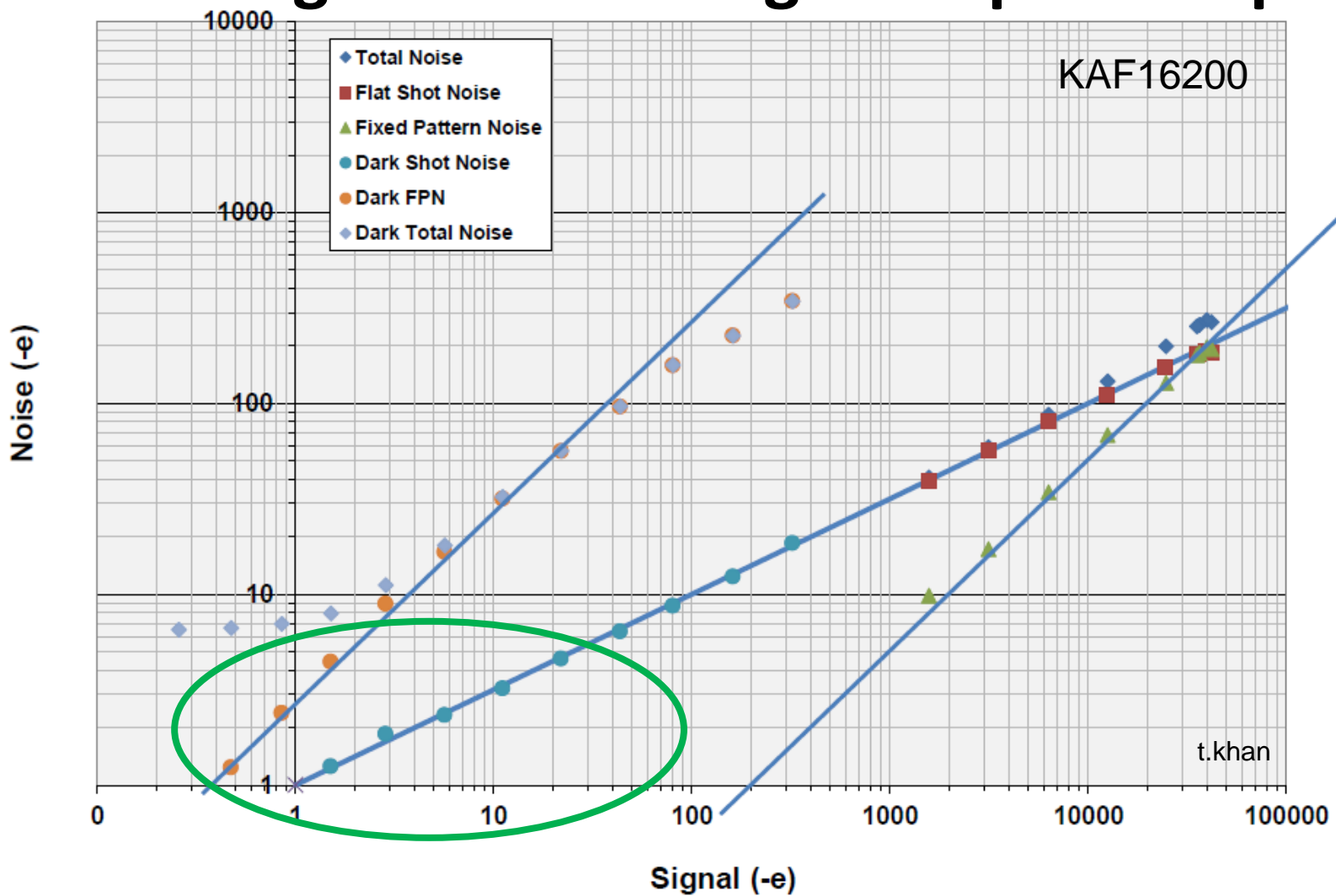


If Trapped Charge is leaking, it can introduce measurement errors: First Dark will have higher value than Second Dark

**When Frame-Differencing Darks this can be a problem**

Camera powered up or light flood

# With flushing before cooling after power up



No Low Level Signal Issues

# Trapped Charge PTC Investigation Methodology

## Use Photon Transfer Methods

- Use PTC characterization data for Read Noise and Camera Gain measurement
- Measure Dark Signal Noise versus Time
- Take pairs of identical dark exposures and difference them to eliminate DFPN (leaves read noise and dark shot noise in remaining difference)
- Two major cases: with and without light flood
- Examine at -15, -20, -25, -30, -35 & -40C operating temperature

$$Total\_noise = \sqrt{Read\_noise^2 + Dark\_shot\_noise^2} \quad (1)$$

$$Dark\_shot\_noise = \sqrt{Total\_noise^2 - Read\_noise^2} \quad (2)$$

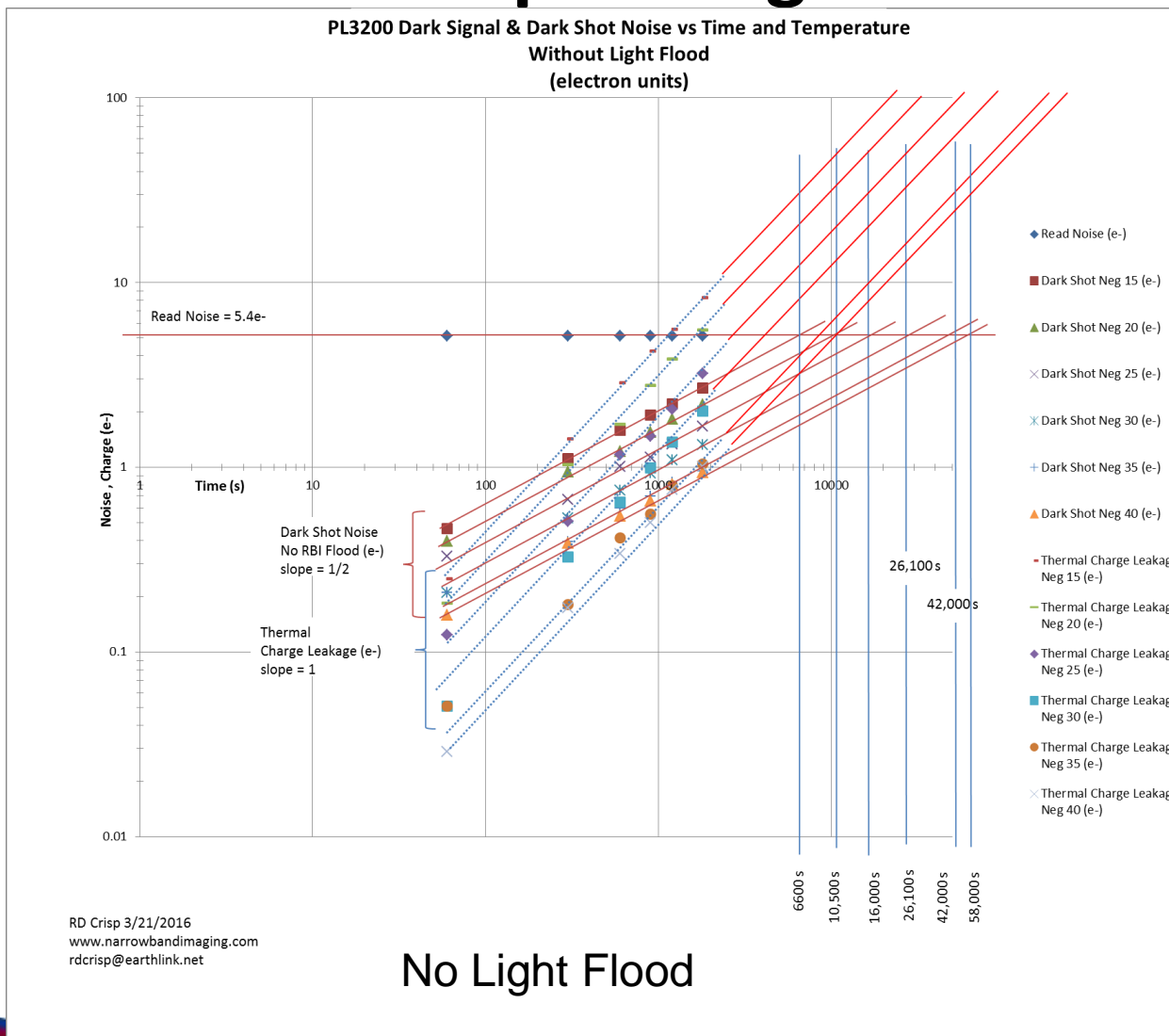
$$Dark\_shot\_noise = \sqrt{Total\_dark\_signal} \quad (3)$$

$$Total\_dark\_signal = Thermal\_dark\_signal + Trap\_leakage \quad (4)$$

For no-light flood case, Trap\_leakage is zero:

$$Total\_dark\_signal = Thermal\_dark\_signal \quad (5)$$

# Baseline Case: no trap leakage

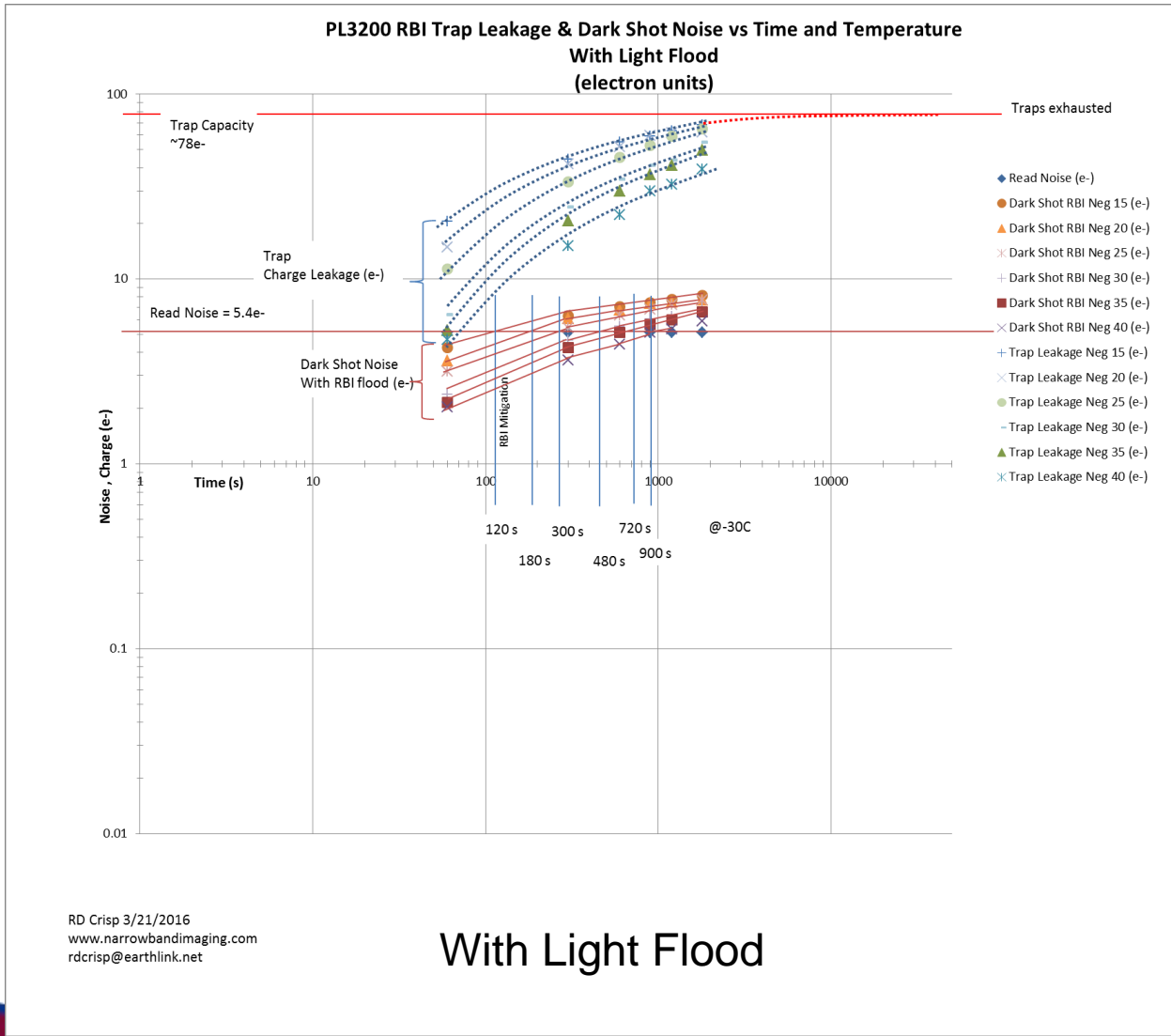


# Calculating Trap Leakage

To determine the trap leakage you use the thermal dark signal data from the non light-flooded case and the Total Noise from the light-flooded case

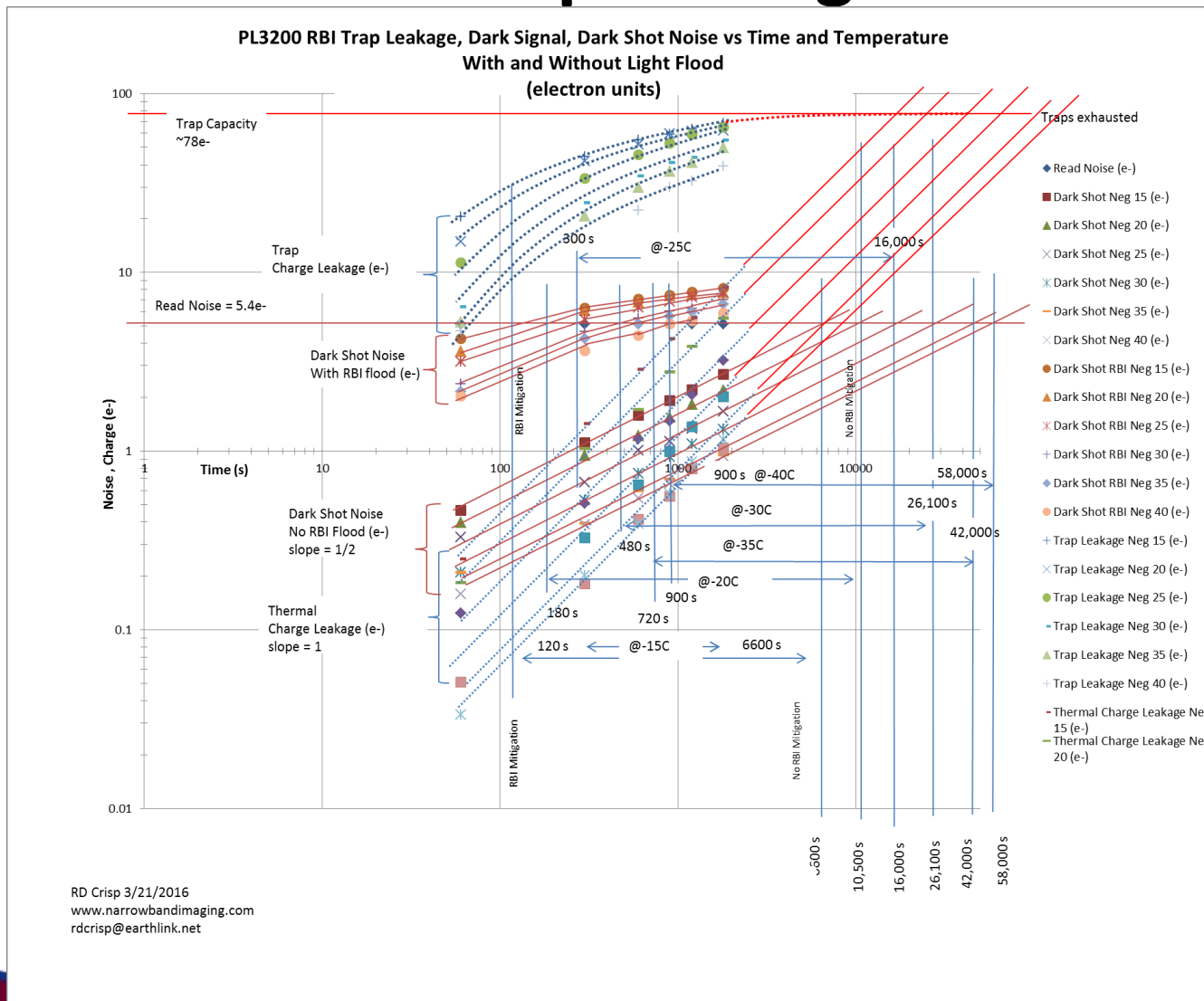
$$\textit{Trap\_leakage} = \textit{Total\_noise}^2 - \textit{Read\_noise}^2 - \textit{Thermal\_dark\_signal} \quad (6)$$

# With Trap Leakage

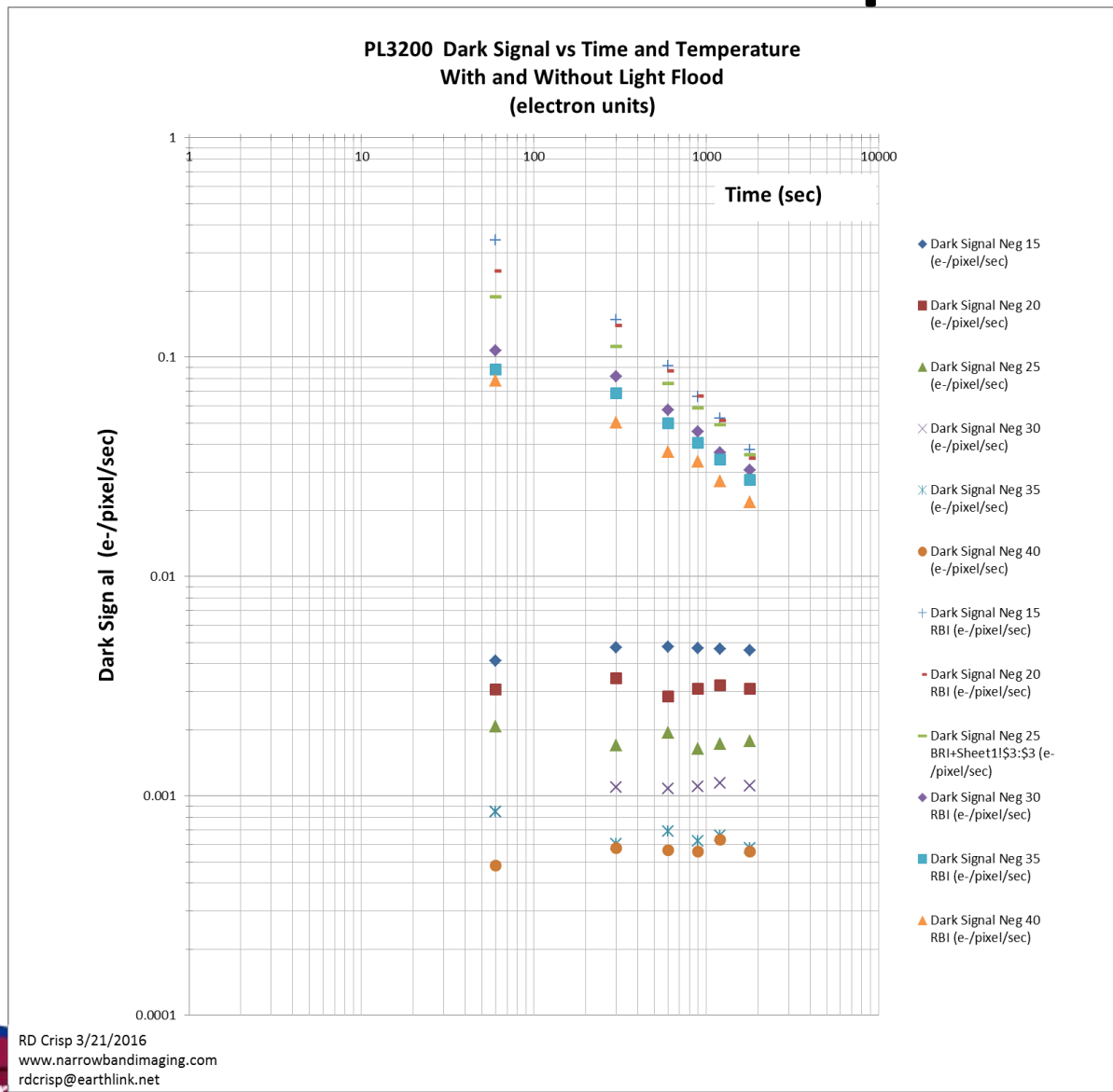




# With and Without Trap Leakage



# Dark Signal With and Without Trap Leakage



# Residual Image Management

# Residual Image



Image

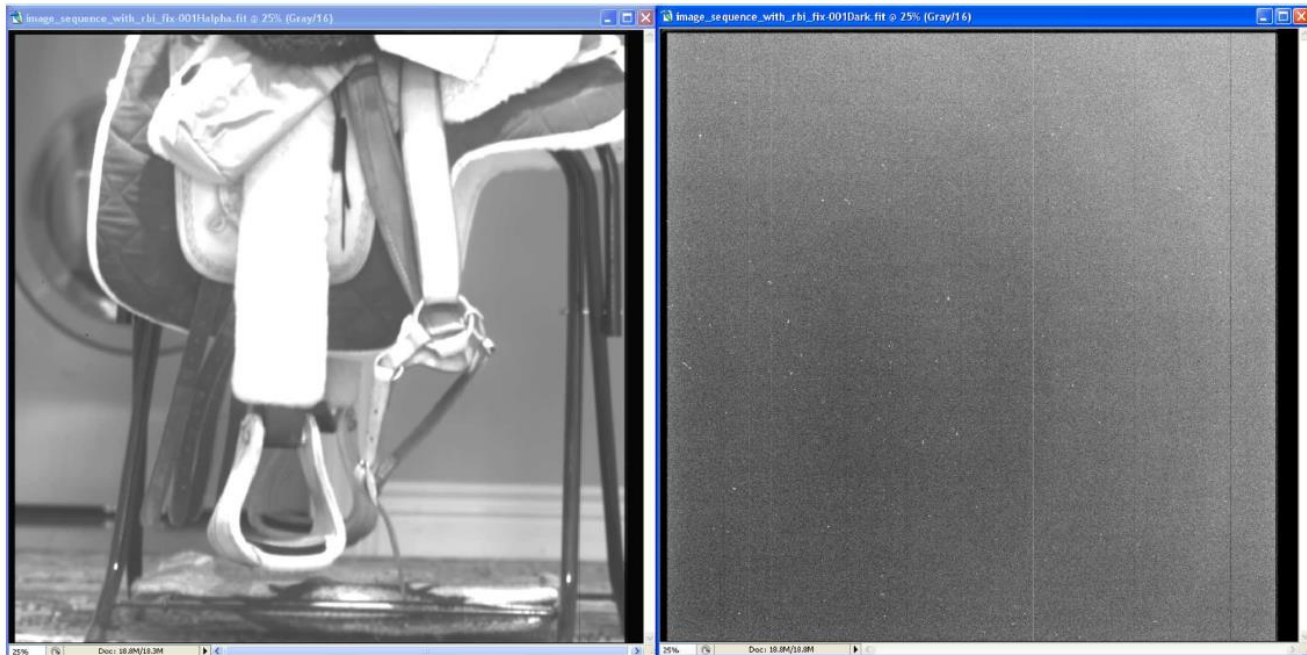


5 Minute Dark  
Immediately  
following  
image



5 Minute Dark  
One hour  
following  
image

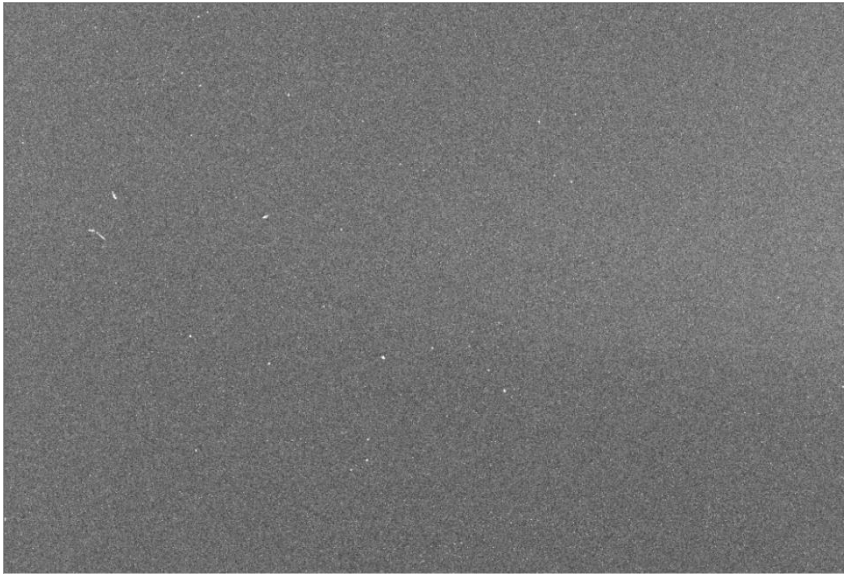
# Residual Image Avoidance using Light Flood



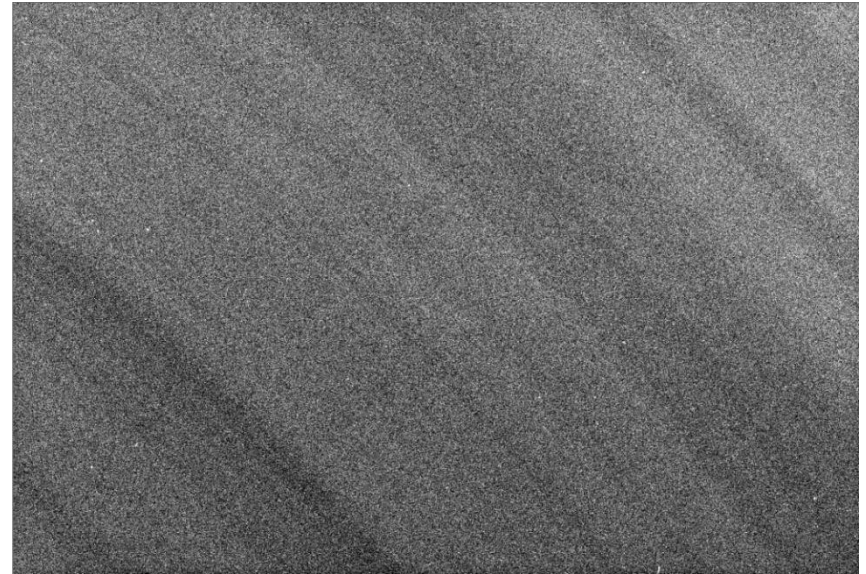
Image

Subsequent dark

# Non Uniformity of Trap Distribution



No Light Flood: Neg 15C,  
300sec dark frame



With Light Flood: Neg 15C,  
300sec dark frame

# Full Calibration (Flats and Darks)



Visible Trap Artifacts Visible

Not Calibrated  
(900 second exposure)



No Trap Artifacts Remain

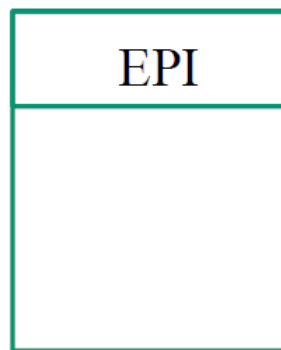
Calibrated  
(900 second exposure)

# Theorized Trap Sources

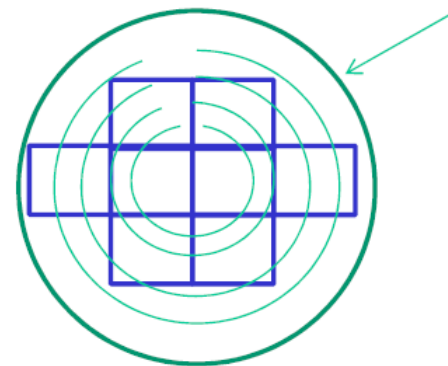


# Theorized Trap Sources

- Epi interface trapping sites
  - Spectral dependence
- Stress-induced trapping sites in lattice from crystal growth process
  - Swirling shapes in darks
- Random bulk defects in crystal lattice
  - No spectral dependence or swirling shapes

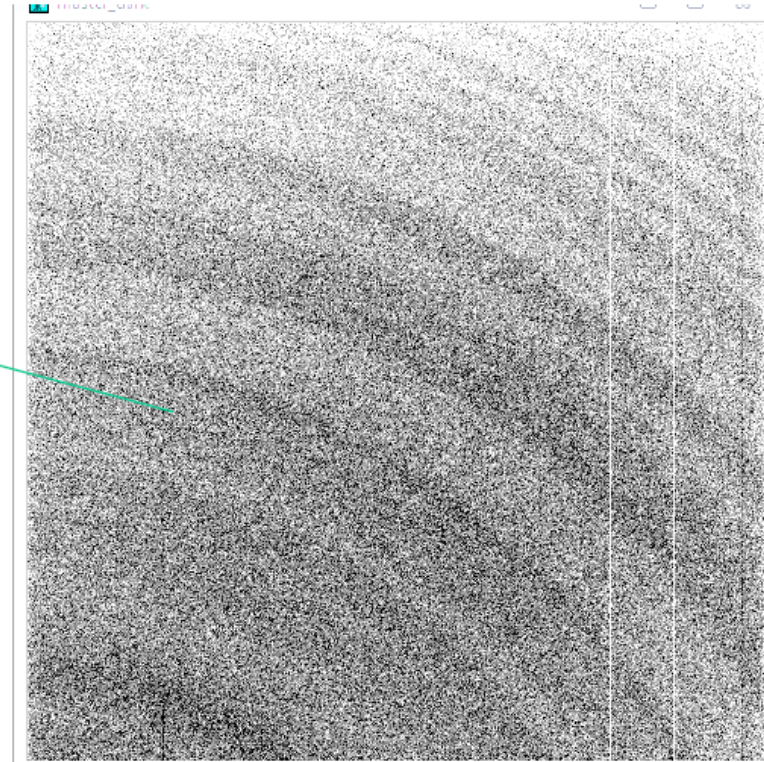
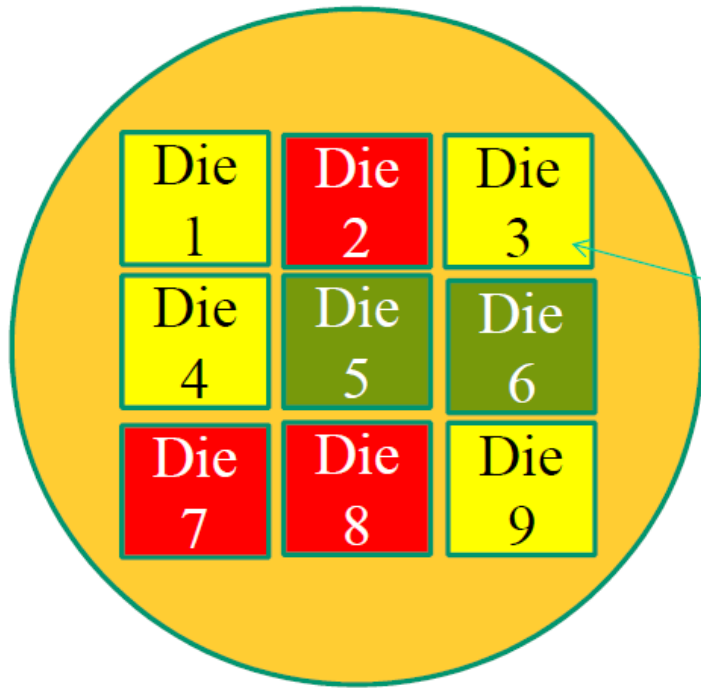


Trapping sites



Residual stresses from crystal growth

# Wafer Mapping Example



# Conclusions

## Photon Transfer Methods can reveal anomalous camera behavior

- Showed that a light flood LED anomalously cycled at power-up in this wor

## Trapped charge can introduce errors in camera EO measurements

- Be cautious when measuring a recently unpowered camera
  - Sensor starts out saturated!
- Be cautious about light exposure before taking dark data
- Be extra cautious with cooled sensors because leakage time is longer

## Photon Transfer Methods can be used to characterize trap capacity and leakage characteristics

- Trap capacity
- Trap leakage
- Temperature behavior

## Light Flood Method is effective at mitigating residual image

- Eliminates residual image
- Removes Dark Fixed Patterns from non-uniform trap distribution

Through Semiconductor IC,  
We Connect People to

*Realize the Dream!*

